Power MOSFET, N-Channel, 600 V, 1.2 Ω

Features

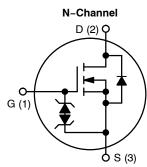
- Low ON Resistance
- Low Gate Charge
- ESD Diode-Protected Gate
- 100% Avalanche Tested
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

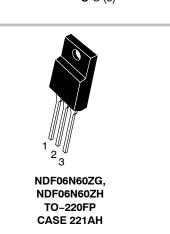
ON

ON Semiconductor®

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V _{DSS} (@ T _{Jmax})	R _{DS(ON)} (MAX) @ 3 A
650 V	1.2 Ω





ABSOLUTE MAXIMUM RATINGS (T_C = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Drain-to-Source Voltage	V _{DSS}	600	V
Continuous Drain Current, $R_{\theta JC}$ (Note 1)	Ι _D	7.1	А
Continuous Drain Current $T_A = 100^{\circ}C, R_{\theta JC}$ (Note 1)	۱ _D	4.5	A
Pulsed Drain Current, V _{GS} @ 10 V	I _{DM}	28	A
Power Dissipation, $R_{\theta JC}$	PD	35	W
Gate-to-Source Voltage	V _{GS}	±30	V
Single Pulse Avalanche Energy, L = 6.3 mH, $I_D = 6.0 A$	E _{AS}	113	mJ
ESD (HBM) (JESD22-A114)	V _{esd}	3000	V
RMS Isolation Voltage (t = 0.3 sec., R.H. \leq 30%, T _A = 25°C) (Figure 13)	V _{ISO}	4500	V
Peak Diode Recovery (Note 2)	dv/dt	4.5	V/ns
MOSFET dV/dt	dV/dt	60	V/ns
Continuous Source Current (Body Diode)	۱ _S	6.0	А
Maximum Temperature for Soldering Leads	TL	260	°C
Operating Junction and Storage Temperature Range	T _J , T _{stg}	–55 to 150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Limited by maximum junction temperature

2. I_{SD} = 6.0 Å, di/dt \leq 100 Å/µs, $V_{DD} \leq$ BV_{DSS} , T_J = +150°C

ORDERING AND MARKING INFORMATION

See detailed ordering, marking and shipping information on page 6 of this data sheet.

THERMAL RESISTANCE

Parameter	Symbol	Value	Unit
Junction-to-Case (Drain)	$R_{ ext{ heta}JC}$	3.6	°C/W
Junction-to-Ambient Steady State (Note 3)	R_{\thetaJA}	50	

3. Insertion mounted

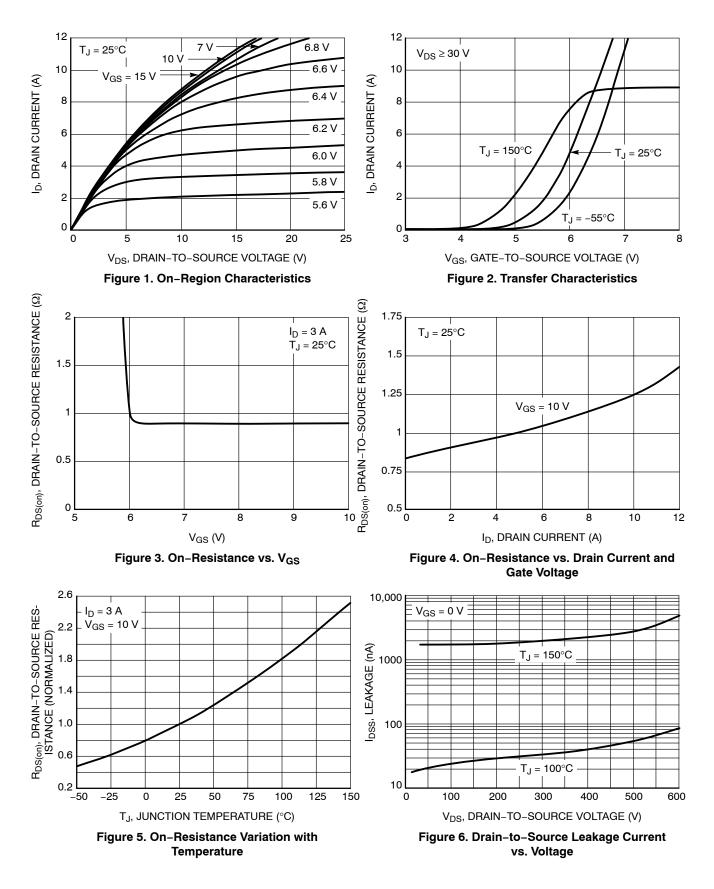
ELECTRICAL CHARACTERISTICS (T_J = 25° C unless otherwise noted)

Characteristic	Test Conditions		Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS							
Drain-to-Source Breakdown Voltage	$V_{GS} = 0 V$, $I_D = 1 mA$		BV _{DSS}	600			V
Breakdown Voltage Temperature Co- efficient	Reference to 25°C, $I_D = 1 \text{ mA}$		$\Delta BV_{DSS}/\Delta T_{J}$		0.6		V/°C
Drain-to-Source Leakage Current	$V_{DS} = 600 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$ 150°C		I _{DSS}			1	μΑ
						50	
Gate-to-Source Forward Leakage	$V_{GS} = \pm 20 \text{ V}$	•	I _{GSS}			±10	μA
ON CHARACTERISTICS (Note 4)							
Static Drain-to-Source On-Resistance	V_{GS} = 10 V, I _D = 3.0 A		R _{DS(on)}		0.98	1.2	Ω
Gate Threshold Voltage	$V_{DS} = V_{GS}$, $I_D = 100 \ \mu A$	1	V _{GS(th)}	3.0	3.9	4.5	V
Forward Transconductance	$V_{DS} = 15 \text{ V}, I_D = 3.0 \text{ A}$		9 _{FS}		5.0		S
OYNAMIC CHARACTERISTICS							
Input Capacitance (Note 5)	V _{DS} = 25 V, V _{GS} = 0 V, f = 1.0 MHz		C _{iss}	738	923	1107	pF
Output Capacitance (Note 5)			C _{oss}	90	106	125	
Reverse Transfer Capacitance (Note 5)			C _{rss}	15	23	30	
Total Gate Charge (Note 5)	V _{DD} = 300 V, I _D = 6.0 A, V _{GS} = 10 V		Qg	15.5	31	47	nC
Gate-to-Source Charge (Note 5)			Q _{gs}	3	6.3	9.5	
Gate-to-Drain ("Miller") Charge (Note 5)			Q _{gd}	8	17	24.5	
Plateau Voltage			V _{GP}		6.4		V
Gate Resistance			Rg		3.2		Ω
RESISTIVE SWITCHING CHARACTERI	STICS		•		•		
Turn-On Delay Time	V_{DD} = 300 V, I _D = 6.0 A, V _{GS} = 10 V, R _G = 5 Ω		t _{d(on)}		13		ns
Rise Time			t _r		17		
Turn-Off Delay Time			t _{d(off)}		30	1	
Fall Time			t _f		28	1	
SOURCE-DRAIN DIODE CHARACTER	STICS (T _C = 25°C unless other	vise noted))		-	-	-
Diode Forward Voltage	$I_{\rm S} = 6.0 \text{ A}, V_{\rm GS} = 0 \text{ V}$		V _{SD}			1.6	V
Reverse Recovery Time	V _{GS} = 0 V, V _{DD} = 30 V		t _{rr}		338		ns
Reverse Recovery Charge	$I_{\rm S} = 6.0$ A, di/dt = 100 A/ μ s		Q _{rr}		2.0	1	μC

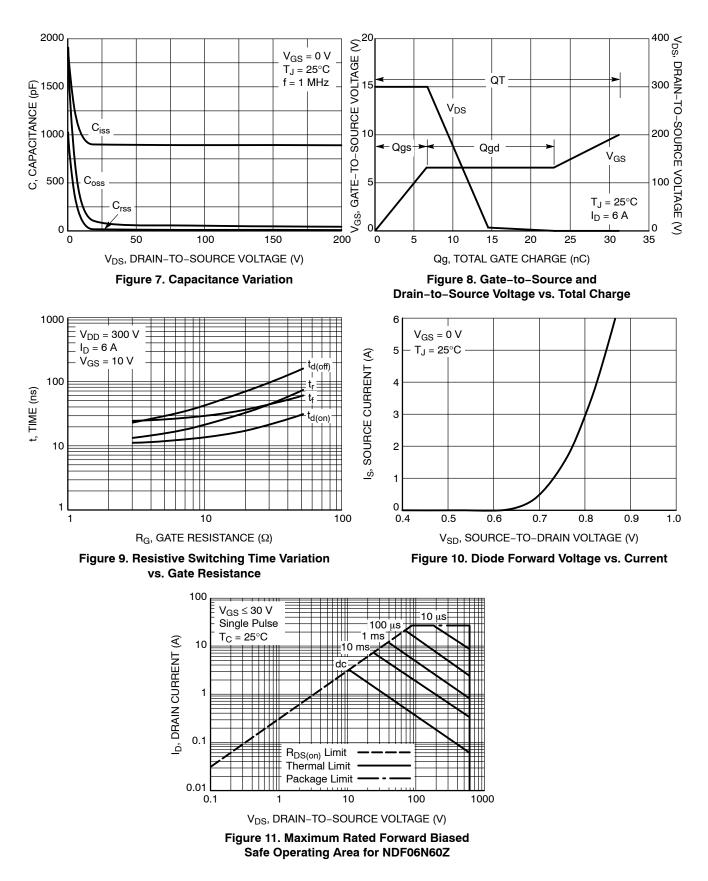
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 4. Pulse Width \leq 380 µs, Duty Cycle \leq 2%.

5. Guaranteed by design.

TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS

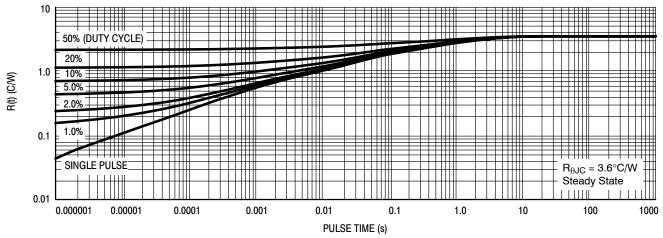
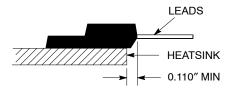


Figure 12. Thermal Impedance for NDF06N60Z





Measurement made between leads and heatsink with all leads shorted together.

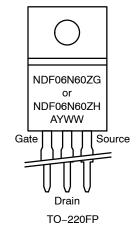
*For additional mounting information, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ORDERING INFORMATION

Order Number	Package	Shipping [†]
NDF06N60ZG	TO–220FP (Pb–Free, Halogen–Free)	50 Units / Rail
NDF06N60ZH	TO-220FP (Pb-Free, Halogen-Free)	50 Units / Rail

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

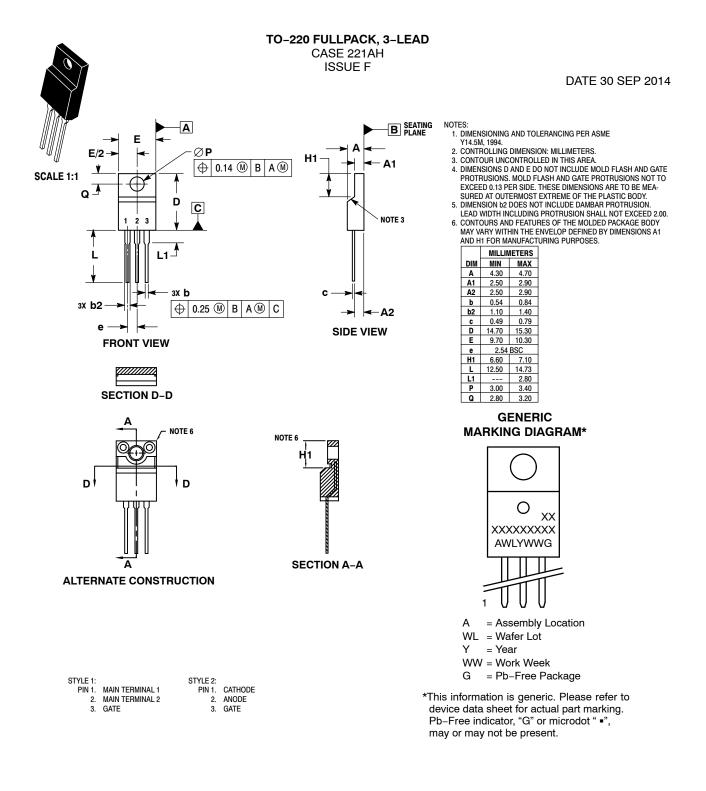
MARKING DIAGRAMS



= Location Code А Υ

- WW = Work Week
- G, H = Pb-Free, Halogen-Free Package

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